

PESDALC10N5VUL

Low Capacitance TVS Array

Description

The PESDALC10N5VUL is low capacitance transient voltage suppressor array for high speed data interface that designed to protect sensitive electronics from damage or latch-up due to ESD lightning, and other voltage induced transient events. All pins are rated to withstand 25kV ESD pulses using the IEC 61000-4-2 air discharge method, which can meet the requirement of level 4.



Circuit Diagram

Feature

- 50W peak pulse power (t_P = 8/20µs)
- DFN2510-10L Package
- Working voltage: 5.0V
- Low clamping voltage
- Low capacitance
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±25KV(air), ±25KV(contact); IEC 61000-4-4 (EFT) 40A (5/50ns)
 IEC 61000-4-5 (Lightning) 4A (8/20us)



Pin1

Marking (Top View)

Applications

- USB 2.0,3.0 Power & Data Line Protection
- DVI & HDMI Port Protection
- Serial ATA Port Protection
- Mobile Handsets
- Digital Cameras and camcorders
- PDA & MP3 Players
- Digital TV and Set-top Boxes
- Other Portable Electronic Components

Mechanical Characteristics

- Lead finish:100% matte Sn(Tin)
- Mounting position: Any
- MSD Level: MSL-1
- Qualified max reflow temperature:260°C
- Pure tin plating: 7 ~ 17 um
- ➢ Pin flatness:≤3mil

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Electronics Parameter

Symbol	Parameter
V _{RWM}	Peak Reverse Working Voltage
I _R	Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
Ι _Τ	Test Current
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
P _{PP}	Peak Pulse Power
CJ	Junction Capacitance
I _F	Forward Current
V _F	Forward Voltage @ I _F



Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V _{RWM}	-	-	-	5.0	V
Breakdown Voltage	V _{BR}	l _t = 1mA	6.0	-	8.5	V
Reverse Leakage Current	I _R	V _{RWM} = 5V	-	-	1	μA
Clamping Voltage ¹⁾	V _c	TLP = 16A, t _p = 100ns	-	13.5	-	V
Dynamic resistance ¹⁾	R _{DYN}	-	-	0.35	-	Ω
Clamping Valtage ²	V _c	I _{PP} = 1A,t _P = 8/20µs	-	9.0	11.0	V
		I _{PP} = 4A,t _P = 8/20µs	-	11.5	14.0	V
Capacitance Between IO and GND	C	V = 0V f = 1MHz	-	0.45	0.65	pF
Capacitance Between IO and I/O	C ¹	$v_R = 0v, I = IWHZ$	-	0.25	0.35	pF

Notes:

1.TLP parameter: $Z_0=50\Omega$, $t_p=100$ ns, $t_r=2$ ns, averaging window from 60ns to 80ns. R_{DYN} is calculated from 4A to 16A. 2.Non-repetitive current pulse, according to IEC61000-4-5.

Absolute maximum rating@25°C

Rating	Symbol	Value	Units
Peak Pulse Power(t _P = 8/20µs)	P _{PP}	50	W
Peak Pulse Current(t _P = 8/20µs)	I _{PP}	4	А
Lead Soldering Temperature	Τ _L	260 (10 sec)	°C
Junction and Storage Temperature Range	T _{J,} T _{STG}	-55~+150	°C
ESD Protection-Contact Discharge	V _{ESD}	±25	kV
ESD Protection-Air Discharge	V _{ESD}	±25	kV

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Typical Characteristics









Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time









Fig 6. TLP Measurement

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Solder Reflow Recommendation



Remark: Pb free for 260°C; Pb for 245°C.

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PCB Design

For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- ➢ Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

Ordering information

Device	Package	Reel	Shipping
PESDALC10N5VUL	DFN2510-10L (Pb-Free)	7"	3000 / Tape & Reel

Load with information



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Product dimension (DFN2510-10L)





Bottom View



Dim	Millim	neters	Inches		
Dim	Min	Мах	Min	Мах	
А	0.45	0.60	0.018	0.024	
A1	0.00	0.05	0.000	0.002	
A2	0.152	2 Ref.	0.006	8 Ref.	
b	0.15	0.25	0.006	0.010	
b1	0.35	0.45	0.014	0.018	
b2	0.12	0.30	0.005	0.012	
D	0.90	1.10	0.035	0.043	
E	2.40	2.60	0.094	0.102	
е	0.40	0.60	0.016	0.024	
К	0.15	0.25	0.006	0.010	
L	0.30	0.50	0.012	0.020	

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